Effect of Heat Treatment on Band Gap of V₂O₅

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The most stable oxide of the vanadium oxide family is V₂O₅. A lot of research effort is focused on it because it has a multitude of functional applications. Here we report on how the heat treatment (600°C, 5 h, air) affects the microstructure and hence, the band gap of V₂O₅. The V₂O₅ powders, initially obtained by simple thermal dissociation (500 °C, 5 h, air) of ammonium metavanadate, followed by heat treatment of pellets, were studied. The structural and optical studies performed using X-ray diffraction (XRD), FESEM and UV-Vis techniques, provide uniquely interesting results which indicate the possibility of band gap tuning by controlling the microstructure.

Keywords: Vanadium Oxide, Multifunctional, Band gap tuning, Microstructure, Heat treatment.

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1. INTRODUCTION

In the periodic table Vanadium is a d-transition metal element with various oxidation states. Therefore, vanadium oxides (V-O) exist in nature in various stereochemistry such as VO₂, V₂O₅, V₃O₅, V₄O₇, VO₅ and V₂O₁₅[1].

Among these the vanadium pentoxide (V₂O₅) is the most stable and widely studied material in the V-O family. The electronic structure of vanadium ions in V₂O₅ has V³⁺ coordination. In such type of transition metal oxides, the d-electrons are spatially confined in partially filled orbitals. They strongly interact with each other, because of the prevalent Coulombic repulsion. These materials are extremely sensitive to small changes in external stimuli such as temperature, pressure, and doping [2, 3]. Vanadium oxides are oxanions of the transition metal vanadium. It shows semiconductor to metal transition (SMT) or insulator to metal transition (IMT). The outstanding properties of V₂O₅ such as band gap in visible region (2.2-2.7 eV), worthy chemical and thermal stability, excellent thermoelectric properties make it suitable for various applications such as solar cell, gas sensors, light modulators, lithium-ion batteries, optical-electrical switches, electrochromic devices, optoelectronic devices, and infrared windows [4-9]. These inorganic materials exhibit highly photochromic and anisotropic electrical properties [6]. Due to its response in visible radiation range V₂O₅ is used as a high-performance photo catalyst which absorbs photon and speed up the chemical reaction [10]. The multi-valence layered structure of V₂O₅ demonstrate high thermo-chromic and electrochemical properties for wide optical band gap. As the most stable among other vanadium oxides, V₂O₅ can be synthesized by various techniques such as chemical different methods, the so-called thermal dissociation is the relatively simple, cost effective, environment friendly vapor deposition, magnetron sputtering, sol-gel method, pulsed laser deposition, electron beam evaporation, electrospinning, spray pyrolysis, hydrothermal and solid-state sintering [11-16]. Amongst and fast technique to prepare micron to sub-micron size powders of V₂O₅ in short reaction time. In the present study, single phase V₂O₅ has been synthesized by thermal dissociation method. Next these powders were consolidated, and heat treated to induce densification by possible solid-state sintering Both types of samples were characterized by XRD, FESEM and UV-Vis spectroscopy techniques.

2. EXPERIMENTAL DETAILS

To prepare the V₂O₅ powders Ammonium metavanadate (NH₄VO₃, 99.0 %, ACS reagent, Sigma Aldrich) was used without any further purification. In the thermal dissociation process, requisite mass of NH₄VO₃ powder was heat treated at 500 °C in a porcelain crucible for 3 h in air. It resulted in an orange colored V₂O₅ powder due to the following reaction [1]:

\[ 2\text{NH}_4\text{VO}_3 \rightarrow \Delta \rightarrow \text{V}_2\text{O}_5 + \text{2NH}_3 + \text{H}_2\text{O} \]

Using these V₂O₅ powders, the orange pellets (~ 1 mm thick and ~ 10 mm diameter) were prepared using a uniaxial press. The pellets were subsequently heat treated at 600 °C for 5 h in air to induce densification by possible solid-state sintering. The as prepared powders and heat treated (HT) pellets were utilized for further studies. The structural characterizations were performed by XRD (Rigaku, Ultima-IV) technique using Cu Kα (λ = 0.154 nm) monochromatic radiation source. The XRD scan were recorded for 2θ range of 10° to 90°. The surface microstructures were studied by using the field emission scanning electron microscopy (FESEM) technique by utilizing a conventional machine (JEOL, JSM-7610FPPlus). The optical properties were studied from 300 to 800 nm by using a standard UV-Vis spectrophotometer (Shimadzu, UV-2600).

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3. RESULT AND DISCUSSION

3.1 X-ray Diffraction

Figure 1 shows the XRD patterns of as prepared powders and heat-treated (HT) V_2O_5 pellets. The patterns match with that of the standard (ICSD collection code: 060767). Thereby, the present results confirm the formation of single phase V_2O_5. It also ensures that both the samples are orthorhombic with lattice parameters of a = 11.51 Å, b = 3.56 Å, and c = 4.36 Å. The major peaks correspond to the presence of (hkl) e.g., (200), (001), (101), (110), (301), (011), and (310) planes at around 2θ values of 15.38°, 20.31°, 21.74°, 26.15°, 31.04°, 32.39°, and 34.31°, respectively. The corresponding inter-planar spacing (d) values are given by 5.75 Å, 4.36 Å, 4.08 Å, 3.40 Å, 2.87 Å, 2.76 Å, and 2.61 Å, respectively. The major peaks of HT sample are more intense compared to those of the as prepared sample. This enhanced intensity represents more crystalline nature of the powder after the heat treatment. The crystallite size (D_DS) was calculated by following Debye-Scherrer (D-S) formula [17]:

$$D_{DS} = k\lambda / \beta \cos \theta,$$

where, k is a constant of value of ~0.9, λ is wavelength of monochromatic source and β is the full width at half maximum. Further, θ is the angle of diffraction. The crystallite sizes of the different planes are mentioned in Table 1 along with their respective miller indices. The average crystallite sizes of both the samples are estimated to be ~23 nm. The crystallite sizes along with the strains were also determined by the well-known Williamson and Hall (W-H) method [18]. The crystallite size (D_WH) and strain (ε) are thus estimated from the corresponding W-H plots by utilizing the following relation:

$$\beta \cos \theta = 4\varepsilon \sin \theta + k\lambda / D_{WH}$$

The relationships between the terms βcosθ and 4sinθ are shown in Figure 2(a) and (b) for the as prepared powders and the HT samples, respectively. The linear fitting shown in these plots estimate the tensile strains of about 0.36 × 10^{-4} and 18.5 × 10^{-4} respectively for the as-prepared and the HT samples. The tensile strain is nearly two orders of magnitude higher in the HT samples reflecting densification-induced strain generation in the microstructure. The higher amount of strain also ensures better intensities of the crystalline peaks in the HT sample. However, the crystallite size for both the samples is still about 23 nm. It supports the results already derived by the D-S technique, as mentioned above. It also confirms that there is no significant change in the fundamental crystalline size after the heat treatment.

3.2 Microstructural Studies

The typical FESEM based photomicrographs of the as prepared powders and the HT pellets are shown in Figure 3(a) and (b), respectively. Both the samples have some relatively smaller approximately equiaxed grains along with some rod-shaped grains. These rod-shaped grains occasionally reflect resemblance to a hexagonal growth pattern. A very approximate and rough grain size distribution data collection was attempted. These data are shown as histograms placed as insets in Figure 3(a) and Figure 3(b) for the as-prepared powders and the HT pellets, respectively. The histograms suggest that average size of grains is about ~440 nm in the case of the as prepared powders but it almost doubles to ~840 nm in the case of the HT samples. Heat treatment induced enhancement in grain size is also reported by other researchers although the experimental conditions are not exactly similar [19-20].

3.3 Optical Properties

The V_2O_5 is a chromogenic material. Its optical properties change on exposure to external stimuli. For instance, incidence of photons causes photochromic changes. Change in applied temperature causes thermo-chromic changes. Similarly, change in applied voltage causes electrochromic changes. As mentioned earlier, the optical properties of the V_2O_5 phase have been studied over visible and near infrared wavelength ranges. The absorbance spectra are shown in Figure 4(a). It exhibits, that the first absorption edge for the HT samples is at around 550 nm in visible range. It is also present in the as prepared sample, but the absorbance of as prepared sample is relatively lower than that of the HT sample, as expected. The relatively higher crystalline peak-intensities in the XRD pattern of the HT sample explains its relatively higher absorbance. This edge shifts to much lower wavelength of 350 nm after heat treatment. This occurs due to inter-band transition [21].
Table 1: Crystallite size of the material with respective miller indices

<table>
<thead>
<tr>
<th>Miller indices (hkl)</th>
<th>(200)</th>
<th>(001)</th>
<th>(101)</th>
<th>(110)</th>
<th>(301)</th>
<th>(011)</th>
<th>(310)</th>
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<tr>
<td>FWHM</td>
<td>0.310</td>
<td>0.385</td>
<td>0.378</td>
<td>0.337</td>
<td>0.360</td>
<td>0.348</td>
<td>0.359</td>
</tr>
<tr>
<td>As prepared</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Heat treated</td>
<td>0.315</td>
<td>0.300</td>
<td>0.335</td>
<td>0.353</td>
<td>0.378</td>
<td>0.388</td>
<td>0.375</td>
</tr>
<tr>
<td>$D_{DS}$</td>
<td>26 nm</td>
<td>21 nm</td>
<td>21 nm</td>
<td>23 nm</td>
<td>24 nm</td>
<td>23 nm</td>
<td>23 nm</td>
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<tr>
<td>As prepared</td>
<td></td>
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<td></td>
<td></td>
</tr>
<tr>
<td>Heat treated</td>
<td>25 nm</td>
<td>26 nm</td>
<td>24 nm</td>
<td>23 nm</td>
<td>22 nm</td>
<td>21 nm</td>
<td>22 nm</td>
</tr>
</tbody>
</table>

**Fig. 2** – The W-H plots with linear fitted data of (a) as prepared sample (b) heat treated sample

**Fig. 3** – FESEM image of (a) as prepared V$_2$O$_5$ and (b) heat treated V$_2$O$_5$ with histogram of grain size distribution

Figure 4(b) represents the transmittance spectra of the as prepared and HT samples. Since the absorbance increases (Figure 4a) the transmittance decreases after heat treatment, as expected. Thus, the larger grain size of the HT sample reduces transmission. On the other hand, the relatively finer grain size, and a relatively less crystalline microstructure (Figure 3a) of the as prepared sample provides possibly more means of transmission (Fig. 4b).

Figure 4(c) represents the Tauc plots of the as prepared and HT samples. These plots are used to determine the respective optical band gaps of these two samples. The band gaps are calculated by the following relation [22].

$$a h v = K (h v - E_g)^n$$

where $a$ is absorption coefficient and is calculated by the Beer Lambert law [22]

$$I/I_0 = e^{-\alpha L}$$

$$\alpha = 2.303 \times A/L,$$

where, $A$ and $L$ are absorbance and length of the sample holder, respectively. Further, $(h v)$ is incident photon energy, $K$ is energy independent constant and $E_g$ is the optical band gap.

For direct band gap transition $n$ equals 1/2 and for indirect band gap transition $n$ equals 2. Based on the usage of the aforesaid equation and linear intercept on the energy axis, the energy required for indirect band gap transition is estimated to be 3.264 eV for the as prepared sample which is expected for the semiconducting orthorhombic structure for the V$_2$O$_5$ materials [23].
Surprisingly, it reduces to 2.45 eV for the HT sample.

This decrease in band gap signifies that relatively lesser amount of energy is required for indirect band gap transition to occur in the HT sample. The lower is the energy requirement, the higher is the chance of carrier transition across the band gap. The higher is the carrier transition, the larger is the carrier concentration. The higher is the carrier concentration the higher is the conductivity. The higher is the conductivity the lower is the resistivity of the sample. It therefore suggests a road map for semiconductor to metal transition.

Other researchers also reported [24] that the absorption edge in V₂O₃ has an Urbach-rule dependence and above 2.4 eV the absorption happens only due to transition at k ≠ 0. Thus, the present results imply that by tuning the microstructure through heat treatment; a situation like semiconductor state to metallic state transition could be affected in V₂O₃ material by a simple, inexpensive approach such as the one used in the current work.

![Graph a](image1)

![Graph b](image2)

**Fig. 4** – (a) Absorbance, (b) Transmission and (c) Tauc plots of as-prepared and heat treated V₂O₃.

### 4. CONCLUSION

The major achievement of the present study lies in identification of a simple inexpensive technique like heat treatment in air to affect reduction of band gap in V₂O₃ material. Thereby it raises a chance to achieve the semiconducting state to metallic state transition as a distinct possibility through tuning of microstructure as well as strain engineering. A simple thermal dissociation results in powders with nanocrystalline crystallite size of about 23 nm which remains unchanged as pellets from this powder are subsequently densified by heat treatment in air at 600 °C for 5 h. Both structures are confirmed to have phase pure orthorhombic structure albeit that the grain size almost doubles to about 840 nm after heat treatment. The stain increases by two orders of magnitude which possibly enhances absorbance but reduces transmission after heat treatment. These factors culminate in achievement of reduction in indirect band gap from 2.64 eV in the as-prepared sample to 2.45 eV in the HT sample, thereby raising a possibility to have tunable band-gap in the current V₂O₃ materials.

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